



TO-92 Plastic-Encapsulate Transistors

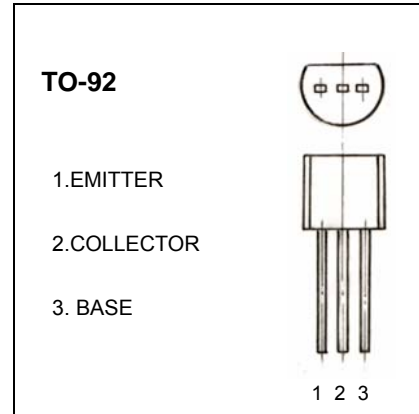
C945 TRANSISTOR (NPN)

FEATURE

- Excellent h_{FE} linearity
- Low noise
- Complementary to A733

MAXIMUM RATINGS ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	50	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current -Continuous	150	mA
P_C	Collector Power Dissipation	400	mW
T_J	Junction Temperature	125	$^{\circ}\text{C}$
T_{stg}	Storage Temperature	-55-125	$^{\circ}\text{C}$

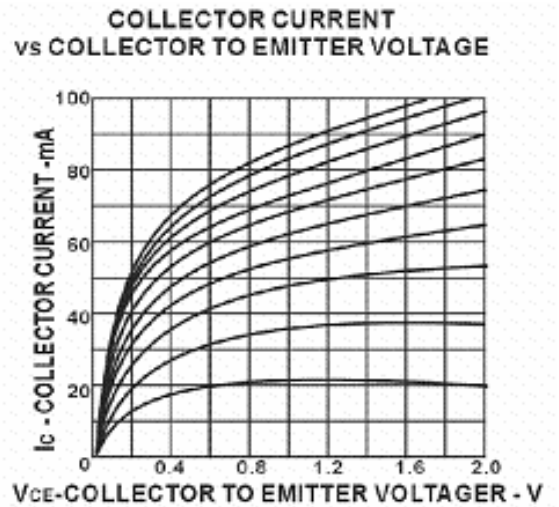
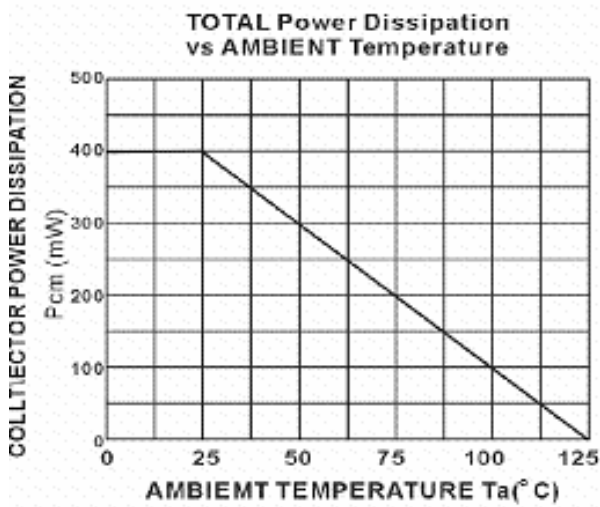


ELECTRICAL CHARACTERISTICS ($T_{amb}=25^{\circ}\text{C}$ unless otherwise specified)

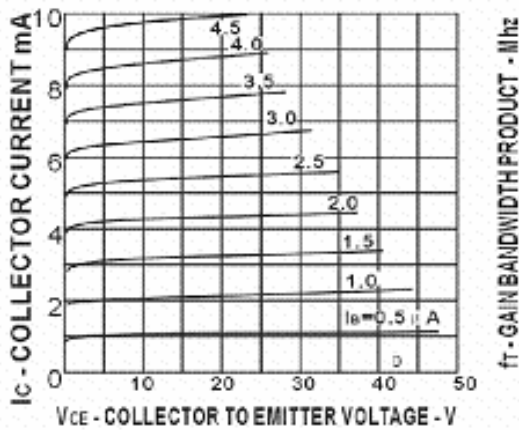
Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=1\text{mA}, I_E=0$	60			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=100\mu\text{A}, I_B=0$	50			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=100\text{mA}, I_C=0$	5			V
Collector cut-off current	I_{CBO}	$V_{CB}=60\text{V}, I_E=0$			0.1	μA
Collector cut-off current	I_{CEO}	$V_{CE}=45\text{V}$			0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=5\text{V}, I_C=0$			0.1	μA
DC current gain	$h_{FE(1)}$	$V_{CE}=6\text{V}, I_C=1\text{mA}$	70		700	
	$h_{FE(2)}$	$V_{CE}=6\text{V}, I_C=0.1\text{mA}$	40			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=100\text{mA}, I_B=10\text{mA}$			0.3	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=100\text{mA}, I_B=10\text{mA}$			1	V
Transition frequency	f_T	$V_{CE}=6\text{V}, I_C=10\text{mA}, f=30\text{MHz}$	200			MHz
Collector output capacitance	C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$			3.0	pF
Noise figure	NF	$V_{CE}=6\text{V}, I_C=0.1\text{mA}$ $R_G=10\text{k}\Omega, f=1\text{kHz}$			10	dB

CLASSIFICATION OF $h_{FE(1)}$

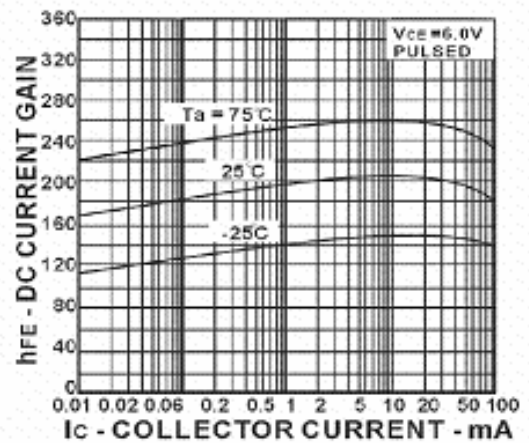
Rank	O	Y	GR	BL
Range	70-140	120-240	200-400	350-700



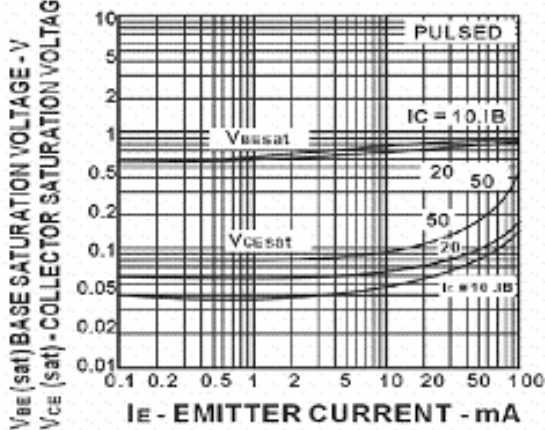
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



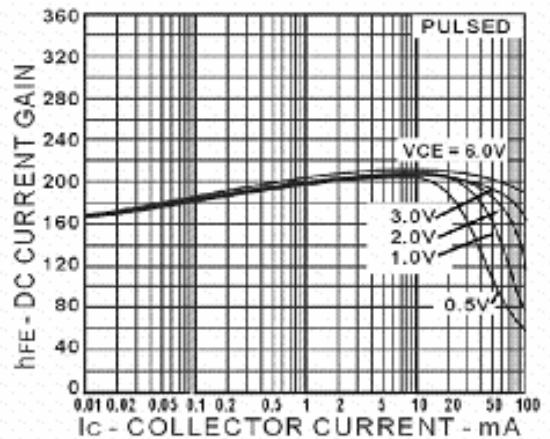
DC CURRENT GAIN vs. COLLECTOR CURRENT



COLLECTOR AND BASE SATURATION VOLTAGE vs. COLLECTOR CURRENT



DC CURRENT GAIN vs. COLLECTOR CURRENT



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